

**TO - 92 BIPOLAR TRANSISTORS
TRANSISTOR(NPN)**

FEATURES

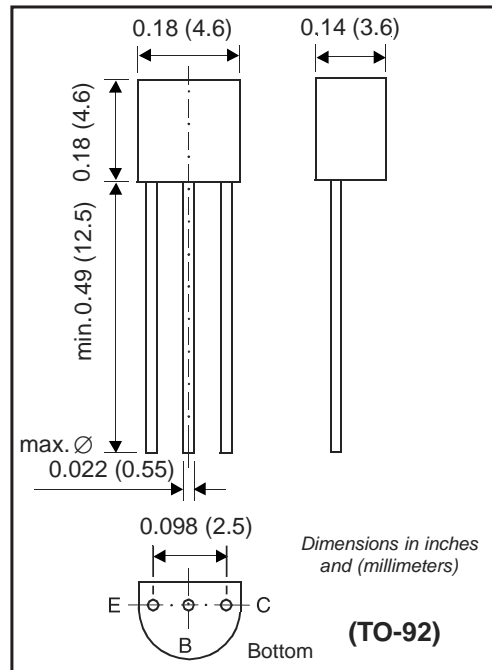
- * Power dissipation
P_{CM}: 625mW(T_{amb}=25°C)
- * Collector current
I_{CM}: 0.6 A
- * Collector-base voltage
V_{(BR)CBO}: 75 V
- * Operating and storage junction temperature range
T_J, T_{stg}: -55°C to +150°C

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: UL 94V-O rate flame retardant
- * Lead: MIL-STD-202E method 208C guaranteed
- * Mounting position: Any
- * Weight: 0.008 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.



MAXIMUM RATINGS (@ T_A = 25°C unless otherwise noted)

RATINGS	SYMBOL	VALUE	UNITS
Max. Steady State Power Dissipation ⁽¹⁾ @T _A =25°C Derate above 25°C	P _D	625	mW
Max. Operating Temperature Range	T _J	150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (@ T_A = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNITS
Thermal Resistance Junction to Ambient	R _{θJA}	-	-	200	°C/W

Notes : 1. Alumina=0.4*0.3*0.024in.99.5% alumina
2. "Fully ROHS Compliant", "100% Sn plating (Pb-free)".

ELECTRICAL CHARACTERISTICS (@TA=25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
----------------	--------	-----	-----	------

OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ($I_C = 10\text{mA}$, $I_B = 0$)	$V_{(BR)CEO}$	40	-	Vdc
Collector-Base Breakdown Voltage ($I_C = 10\text{uA}$, $I_E = 0$)	$V_{(BR)CBO}$	75	-	Vdc
Emitter-Base Breakdown Voltage ($I_E = 10\text{uA}$, $I_C = 0$)	$V_{(BR)EBO}$	6.0	-	Vdc
Collector Cutoff Current ($V_{CE} = 60\text{Vdc}$, $V_{EB(off)} = 3.0\text{Vdc}$)	I_{CEX}	-	0.01	μA
Collector Cutoff Current ($V_{CB} = 60\text{Vdc}$, $I_E = 0$) ($V_{CB} = 60\text{Vdc}$, $I_E = 0$, $T_A = 150^\circ\text{C}$)	I_{CBO}	-	0.01 10	μA
Emitter Cutoff Current ($V_{EB} = 3.0\text{Vdc}$, $I_C = 0$)	I_{EBO}	-	0.01	μA
Base Cutoff Current ($V_{CE} = 60\text{Vdc}$, $V_{EB(off)} = 3.0\text{Vdc}$)	I_{BL}	-	20	nA

ON CHARACTERISTICS

DC Current Gain ($I_C = 10\text{mA}$, $V_{CE} = 10\text{Vdc}$, $T_A = -55^\circ\text{C}$) ($I_C = 500\text{mA}$, $V_{CE} = 10\text{Vdc}$) (1)	hFE	35 40	- -	-
Collector-Emitter Saturation Voltage (1) ($I_C = 150\text{mA}$, $I_B = 15\text{mA}$) ($I_C = 500\text{mA}$, $I_B = 50\text{mA}$)	$V_{CE(sat)}$	- -	0.3 1.0	Vdc
Base-Emitter Saturation Voltage (1) ($I_C = 150\text{mA}$, $I_B = 15\text{mA}$) ($I_C = 500\text{mA}$, $I_B = 50\text{mA}$)	$V_{BE(sat)}$	0.6 -	1.2 2.0	Vdc

SMALL-SIGNAL CHARACTERISTICS

Current-Gain-Bandwidth Product (2) ($I_C = 20\text{mA}$, $V_{CE} = 20\text{Vdc}$, $f = 100\text{MHz}$)	f_T	300	-	MHz
Input Capacitance ($V_{EB} = 0.5\text{Vdc}$, $I_C = 0$, $f = 1.0\text{MHz}$)	C_{ibo}	-	25	pF
Input Impedance ($I_C = 1.0\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$) ($I_C = 10\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$)	h_{ie}	2.0 0.25	8.0 1.25	kohms
Voltage Feedback Ratio ($I_C = 1.0\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$) ($I_C = 10\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$)	h_{re}	- -	8.0 4.0	$\times 10^{-4}$
Small-Signal Current Gain ($I_C = 1.0\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$) ($I_C = 10\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$)	h_{fe}	50 75	300 375	-
Output Admittance ($I_C = 1.0\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$) ($I_C = 10\text{mA}$, $V_{CE} = 10\text{Vdc}$, $f = 1.0\text{kHz}$)	h_{oe}	5.0 25	35 200	μmhos
Collector Base Time Constant ($I_E = 20\text{mA}$, $V_{CB} = 20\text{Vdc}$, $f = 31.8\text{MHz}$)	$\tau_{b,Cc}$	-	150	ps
Noise Figure ($I_C = 100\text{uA}$, $V_{CE} = 10\text{Vdc}$, $R_S = 1.0\text{kohms}$, $f = 1.0\text{kHz}$)	NF	-	4.0	dB

SWITCHING CHARACTERISTICS

Delay Time Rise Time	($V_{CC} = 30\text{Vdc}$, $V_{BE(off)} = -0.5\text{Vdc}$, $I_C = 150\text{mA}$, $I_{B1} = 15\text{mA}$)	t_d t_r	- -	10 25	ns
Storage Time Fall Time	($V_{CC} = 30\text{Vdc}$, $I_C = 150\text{mA}$, $I_{B1} = I_{B2} = 15\text{mA}$)	t_s t_f	- -	225 60	ns

NOTES : 1. Pulse Test: Pulse Width $\leq 300\text{ms}$, Duty Cycle $\leq 2.0\%$
2. f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity

RATING AND CHARACTERISTICS CURVES (PN2222A)

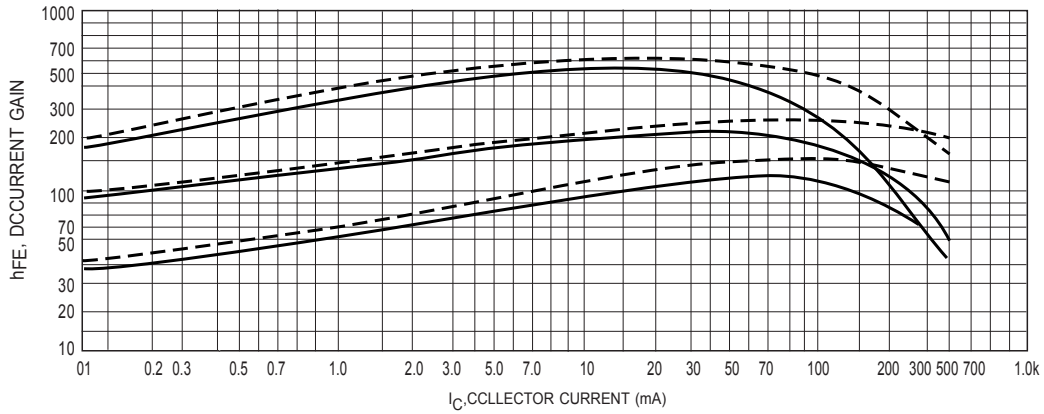


Figure 1. DC Current Gain

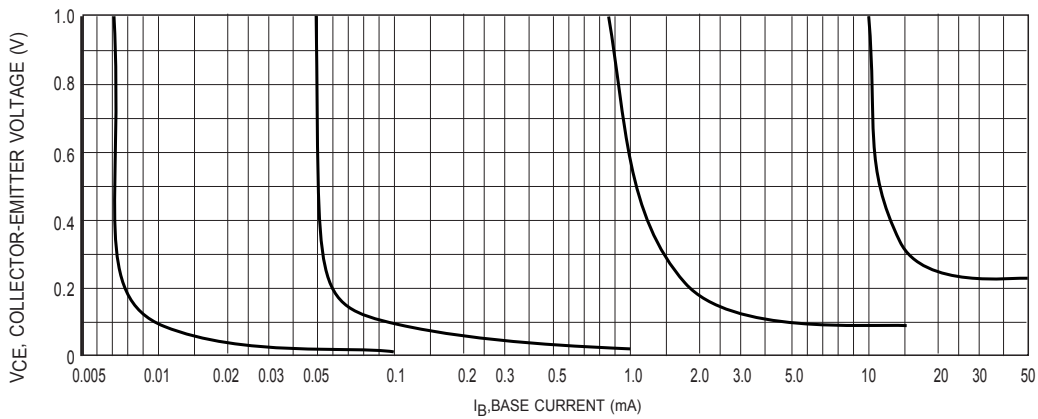


Figure 2. Collector Saturation Region

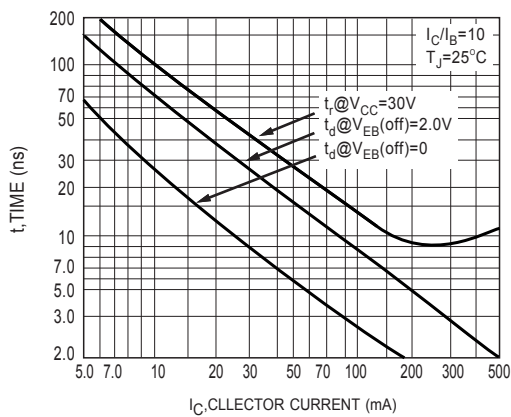


Figure 3. Turn-On Time

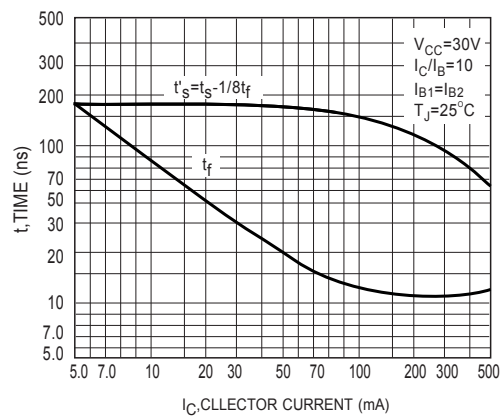


Figure 4. Turn-Off Time

RATING AND CHARACTERISTICS CURVES (PN2222A)

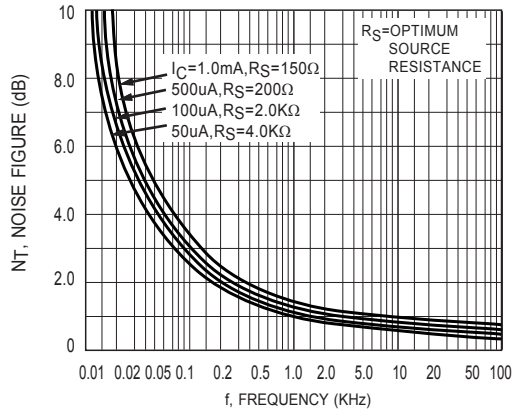


Figure 5. Frequency Effects

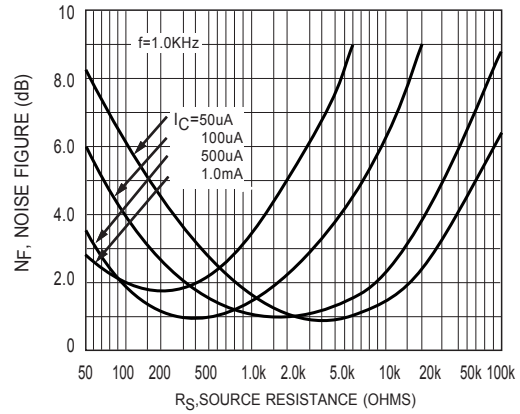


Figure 6. Source Resistance Effects

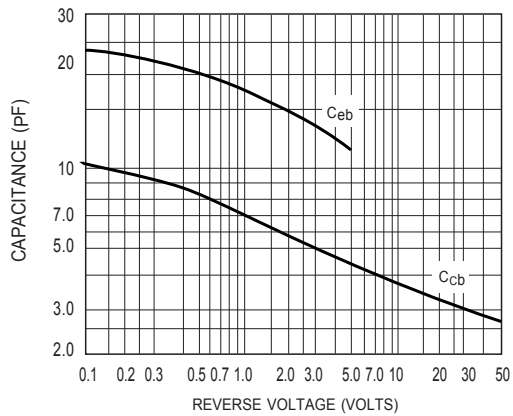


Figure 7. Capacitances

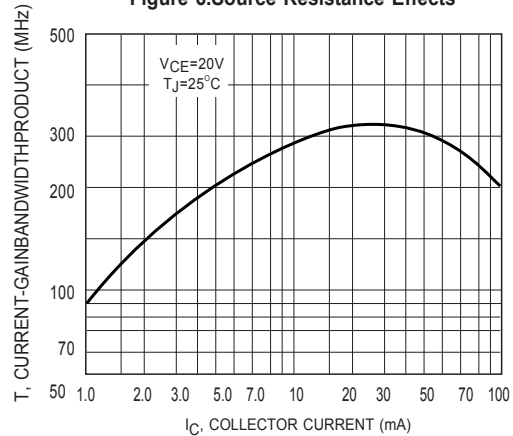


Figure 8. Current-Gain Bandwidth Product

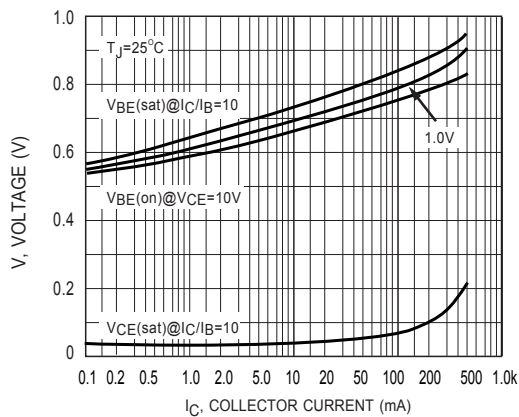


Figure 9. "On" Voltages

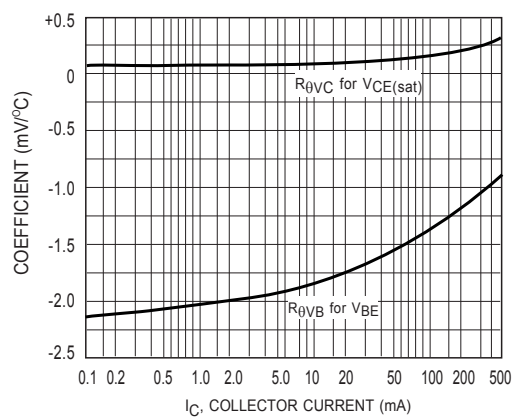


Figure 10. Temperature Coefficients

DISCLAIMER NOTICE

Rectron Inc reserves the right to make changes without notice to any product specification herein, to make corrections, modifications, enhancements or other changes. Rectron Inc or anyone on its behalf assumes no responsibility or liability for any errors or inaccuracies. Data sheet specifications and its information contained are intended to provide a product description only. "Typical" parameters which may be included on RECTRON data sheets and/ or specifications can and do vary in different applications and actual performance may vary over time. Rectron Inc does not assume any liability arising out of the application or use of any product or circuit.

Rectron products are not designed, intended or authorized for use in medical, life-saving implant or other applications intended for life-sustaining or other related applications where a failure or malfunction of component or circuitry may directly or indirectly cause injury or threaten a life without expressed written approval of Rectron Inc. Customers using or selling Rectron components for use in such applications do so at their own risk and shall agree to fully indemnify Rectron Inc and its subsidiaries harmless against all claims, damages and expenditures.

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru